FAIRCHILD SEMICONDUCTOR™

December 1997

74LCX74
Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop with 5V Tolerant Inputs

General Description

The LCX74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q, $\overline{Q}$) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

LOW input to $\overline{S}_D$ (Set) sets Q to HIGH level

LOW input to $\overline{C}_D$ (Clear) sets Q to LOW level

Clear and Set are independent of clock

Simultaneous LOW on $\overline{C}_D$ and $\overline{S}_D$ makes both Q and $\overline{Q}$ HIGH

Features

- 5V tolerant inputs
- 7.0 ns t_{PD} max, 10 µA I_{CCQ} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal
- 2.0V–3.6V V_{CC} supply operation
- ±24 mA output drive
- Implements patented noise/EMI reduction circuitry
- Functionally compatible with 74 series 74
- Latch-up performance exceeds 500 mA
- ESD performance:
  Human body model > 2000V
  Machine model > 200V

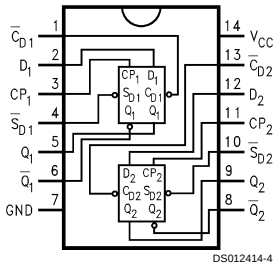
Ordering Code:

Order Number	Package Number	Package Description
74LCX74M	M14A	16-Lead (0.150" Wide) Molded Small Outline Package, SOIC, JEDEC
74LCX74SJ	M14D	14-Lead Small Outline Package, SOIC, EIAJ
74LCX74MTC	MTC14	14-Lead Thin Shrink Small Outline Package, TSSOP

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram

Pin Assignment for SOIC and TSSOP



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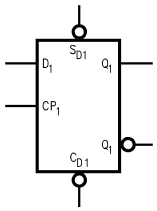
Logic Symbol



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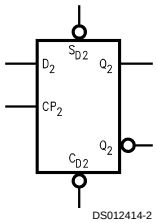

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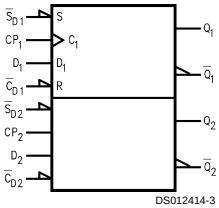
IEEE/IEC



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Pin Descriptions

Pin Names	Description
D_1, D_2	Data Inputs
CP_1, CP_2	Clock Pulse Inputs
$\overline{C}_{D1}$, $\overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}$, $\overline{S}_{D2}$	Direct Set Inputs
Q_1, $\overline{Q}_1$, Q_2, $\overline{Q}_2$	Outputs

Truth Table

(Each Half)

Inputs				Outputs	
$\overline{S}_D$	$\overline{C}_D$	CP	D	Q	$\overline{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H
H	H	⌐	H	H	L
H	H	⌐	L	L	H
H	H	L	X	Q_0	$\overline{Q}_0$

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
⌐ = LOW-to-HIGH Clock Transition
$Q_0(\overline{Q}_0)$ = Previous $Q(\overline{Q})$ before LOW-to-HIGH Transition of Clock

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +7.0		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	Output in High or Low State (Note 2)	V
I_{IK}	DC Input Diode Current	−50	V_I < GND	mA
I_{OK}	DC Output Diode Current	−50	V_O < GND	mA
		+50	V_O > V_{CC}	
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current per Supply Pin	±100		mA
I_{GND}	DC Ground Current per Ground Pin	±100		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Units
V_{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage	HIGH or LOW State	0	V_{CC}	V
I_{OH}/I_{OL}	Output Current	V_{CC} = 3.0V − 3.6V		±24	mA
		V_{CC} = 2.7V		±12	
T_A	Free-Air Operating Temperature		−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, V_{IN} = 0.8V–2.0V, V_{CC} = 3.0V		0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V_{CC}	T_A = −40°C to +85°C		Units
			(V)	Min	Max	
V_{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V_{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V_{OH}	HIGH Level Output Voltage	I_{OH} = −100 µA	2.7–3.6	V_{CC} − 0.2		V
		I_{OH} = −12 mA	2.7	2.2		V
		I_{OH} = −18 mA	3.0	2.4		V
		I_{OH} = −24 mA	3.0	2.2		V
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7–3.6		0.2	V
		I_{OL} = 12 mA	2.7		0.4	V
		I_{OL} = 16 mA	3.0		0.4	V
		I_{OL} = 24 mA	3.0		0.55	V
I_I	Input Leakage Current	0 ≤ V_I ≤ 5.5V	2.7–3.6		±5.0	µA
I_{OFF}	Power-Off Leakage Current	V_I or V_O = 5.5V	0		10	µA
I_{CC}	Quiescent Supply Current	V_I = V_{CC} or GND	2.7–3.6		10	µA
		3.6V ≤ V_I ≤ 5.5V	2.7–3.6		±10	µA
ΔI_{CC}	Increase in I_{CC} per Input	V_{IH} = V_{CC} −0.6V	2.7–3.6		500	µA

AC Electrical Characteristics

Symbol	Parameter	$T_A = -40^\circ C$ to $+85^\circ C$, $C_L = 50pF$, $R_L = 500\Omega$				Units
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$		
		Min	Max	Min	Max	
f_{MAX}	Maximum Clock Frequency	150		150		MHz
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	ns
t_{PLH}	CP_n to Q_n or $\overline{Q}_n$	1.5	7.0	1.5	8.0	
t_{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	ns
t_{PLH}	$\overline{C}_{Dn}$ or $\overline{S}_{Dn}$ to Q_n or $\overline{Q}_n$	1.5	7.0	1.5	8.0	
t_S	Setup Time	2.5		2.5		ns
t_H	Hold Time	1.5		1.5		ns
t_W	Pulse Width CP	3.3		3.3		ns
t_W	Pulse Width and $\overline{C}_D$, $\overline{S}_D$	3.3		3.6		ns
t_{rem}	Removal Time	2.5		3.0		ns
t_{OSHL}	Output to Output Skew		1.0			ns
t_{OSLH}	(Note 4)		1.0			

Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

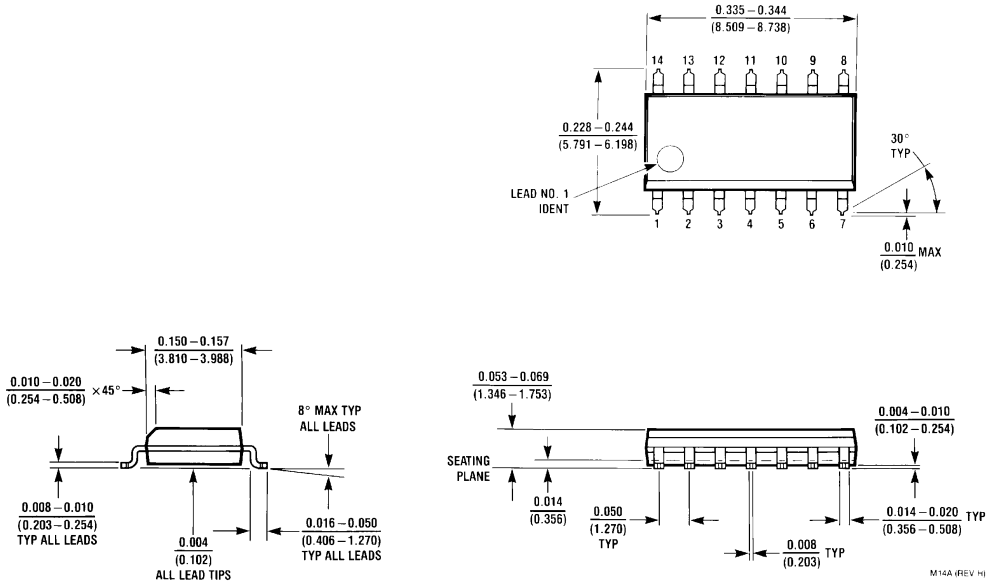
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25^\circ C$ Typical	Unit
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50$ pF, $V_{IH} = 3.3V$, $V_{IL} = 0V$	3.3	−0.8	V

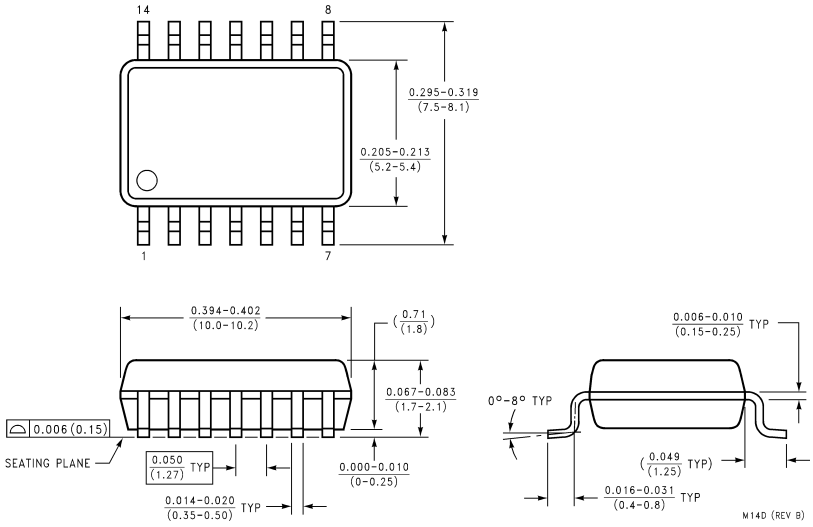
Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	V_{CC} = Open, $V_I = 0V$ or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}, f = 10 MHz	25	pF

Physical Dimensions inches (millimeters) unless otherwise noted

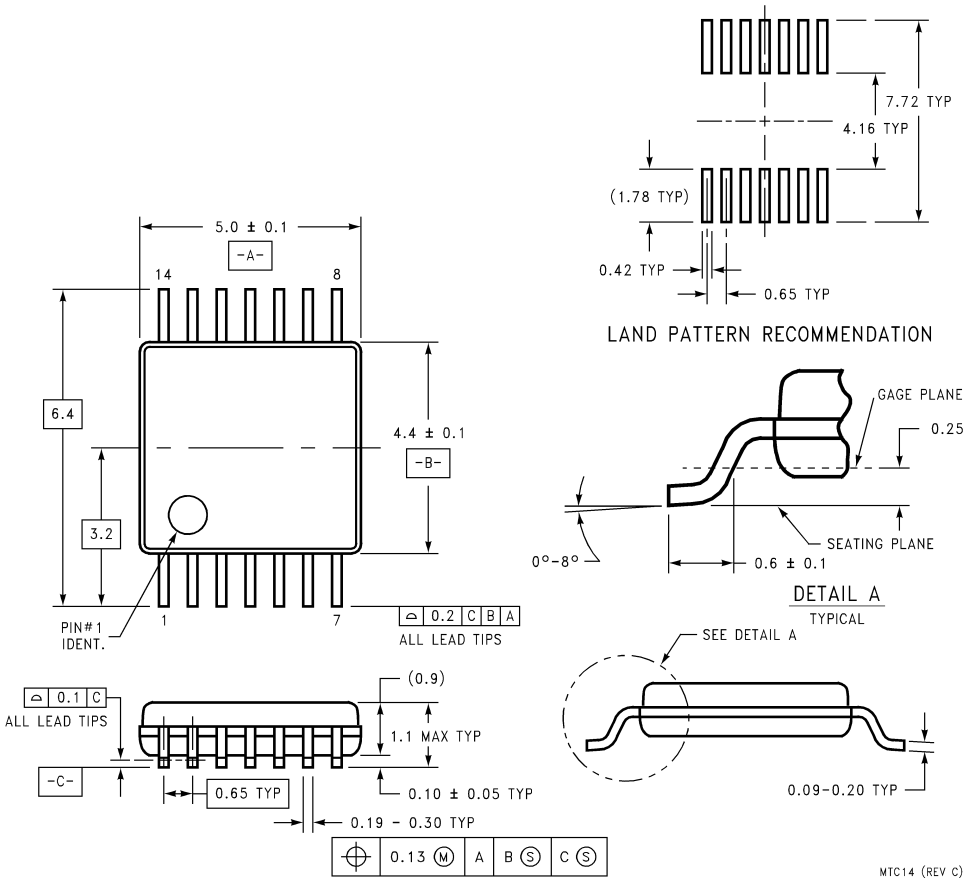


16-Lead (0.0150" Wide) Molded Small Outline Package JEDEC
Package Number M14A



14-Lead Small Outline Package EIAJ (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Thin Shrink Small Outline Package, JEDEC
Package Number MTC14

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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